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DUAL RS-232 DRIVER/RECEIVER WITH IEC61000-4-2 PROTECTION

FEATURES

- Meets or Exceeds TIA/RS-232-F and ITU Recommendation V.28
- Operates From a Single 5-V Power Supply With 1.0-μF Charge-Pump Capacitors
- Operates up to 250 kbit/s
- Two Drivers and Two Receivers
- ±30-V Input Levels
- Low Supply Current . . . 8 mA Typical
- ESD Protection for RS-232 Bus Pins
 - ±15-kV Human-Body Model (HBM)
 - ±8-kV IEC61000-4-2, Contact Discharge
 - ±15-kV IEC61000-4-2, Air-Gap Discharge

APPLICATIONS

- TIA/RS-232-F
- Battery-Powered Systems
- Terminals
- Modems
- Computers

(TOP VIEW) 16**∏** Vcc. V_{S+} [] 15 GND C1− ¶ 3 14 DOUT1 C2+ RIN1 4 13 C2- [ROUT1 5 12 11 DIN1 V_{S−} **[**] 6 DOUT2 17 10 DIN2 9∏ ROUT2 RIN2

D, DW, N, NS, OR PW PACKAGE

DESCRIPTION/ORDERING INFORMATION

The TRS232E is a dual driver/receiver that includes a capacitive voltage generator to supply TIA/RS-232-F voltage levels from a single 5-V supply. Each receiver converts TIA/RS-232-F inputs to 5-V TTL/CMOS levels. This receiver has a typical threshold of 1.3 V, a typical hysteresis of 0.5 V, and can accept ±30-V inputs. Each driver converts TTL/CMOS input levels into TIA/RS-232-F levels. The driver, receiver, and voltage-generator functions are available as cells in the Texas Instruments LinASIC™ library.

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Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

LinASIC is a trademark of Texas Instruments.



ORDERING INFORMATION

T _A	PACKAGE ⁽¹⁾⁽²⁾		ORDERABLE PART NUMBER	TOP-SIDE MARKING	
	PDIP – N	Tube of 25	TRS232ECN	TRS232ECN	
	SOIC – D	Tube of 40	TRS232ECD	TDC222FC	
	30IC - D	Reel of 2500	TRS232ECDR	TRS232EC	
000 to 7000	COIC DW	Tube of 40	TRS232ECDW	TDCCCCC	
0°C to 70°C	SOIC – DW	Reel of 2000	TRS232ECDWR	TRS232EC	
	SOP - NS	Reel of 2000	TRS232ECNSR	PREVIEW	
	TCCOD DW	Tube of 25	TRS232ECPW	DUSSEC	
	TSSOP – PW	Reel of 2000	TRS232ECPWR	RU32EC	
	PDIP – N	- N Tube of 25 TRS232EIN		TRS232EIN	
	COIC D	Tube of 40	TRS232EID	TDCCCCT	
	SOIC – D	Reel of 2500	TRS232EIDR	TRS232EI	
4000 to 0500	COIC DW	Tube of 40	TRS232EIDW	TDOOOSEI	
–40°C to 85°C	SOIC – DW	Reel of 2000	TRS232EIDWR	TRS232EI	
	SOP - NS	Reel of 2000	TRS232EINSR	PREVIEW	
	TCCOD DW	Tube of 25	TRS232EIPW	DURACI	
	TSSOP – PW	Reel of 2000	TRS232EIPWR	RU32EI	

- (1) Package drawings, thermal data, and symbolization are available at www.ti.com/packaging.
- (2) For the most current package and ordering information, see the Package Option Addendum at the end of this document, or see the TI website at www.ti.com.

FUNCTION TABLES

Each Driver⁽¹⁾

INPUT DIN	OUTPUT DOUT
L	Н
Н	L

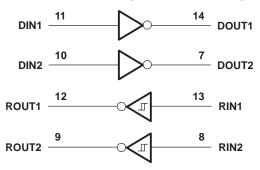
(1) H = high level, L = low level

Each Receiver⁽¹⁾

INPUT RIN	OUTPUT ROUT
L	Н
Н	L

(1) H = high level, L = low level

LOGIC DIAGRAM (POSITIVE LOGIC)



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Absolute Maximum Ratings(1)

over operating free-air temperature range (unless otherwise noted)

			MIN	MAX	UNIT
V _{CC}	Input supply voltage range (2)		-0.3	6	V
V _{S+}	Positive output supply voltage range		V _{CC} - 0.3	15	V
V _{S-}	Negative output supply voltage range		-0.3	-15	V
	land to take the new years	Driver	-0.3	V _{CC} + 0.3	V
VI	Input voltage range	Receiver		±30	V
Vo	Output well-and and and	DOUT	V _{S-} - 0.3	V _{S+} + 0.3	
	Output voltage range	ROUT	-0.3	V _{CC} + 0.3	V
	Short-circuit duration	DOUT		Unlimited	
		D package		73	
		DW package		57	
θ_{JA}	Package thermal impedance (3)(4)	N package		67	°C/W
		NS package		64	
		PW package		108	
T_{J}	Operating virtual junction temperature	,		150	°C
T _{stg}	Storage temperature range		-65	150	°C

⁽¹⁾ Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

Recommended Operating Conditions

			MIN	NOM	MAX	UNIT
V _{CC}	Supply voltage	4.5	5	5.5	V	
V _{IH}	High-level input voltage (DIN1, DIN2)	2			V	
V _{IL}	Low-level input voltage (DIN1, DIN2)			0.8	V	
	Receiver input voltage (RIN1, RIN2)				±30	V
_		TRS232EC	0		70	°C
1A	Operating free-air temperature	-40		85		

Electrical Characteristics(1)

over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted) (see Figure 4)

	PARAMETER	TE	ST CONDITIONS	MIN	TYP ⁽²⁾	MAX	UNIT
Icc	Supply current	$V_{CC} = 5.5 \text{ V},$	All outputs open, T _A = 25°C		8	10	mA

Test conditions are C1–C4 = 1 μ F at V_{CC} = 5 V ± 0.5 V. All typical values are at V_{CC} = 5 V and T_A = 25°C.

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All voltages are with respect to network GND.

Maximum power dissipation is a function of $T_J(max)$, θ_{JA} , and T_A . The maximum allowable power dissipation at any allowable ambient temperature is $P_D = (T_J(max) - T_A)/\theta_{JA}$. Operating at the absolute maximum T_J of 150°C can affect reliability. The package thermal impedance is calculated in accordance with JESD 51-7.



DRIVER SECTION

Electrical Characteristics⁽¹⁾

over recommended ranges of supply voltage and operating free-air temperature range

	PARAMETER		TEST CONDITIONS			TYP ⁽²⁾	MAX	UNIT
V_{OH}	High-level output voltage	DOUT	$R_L = 3 \text{ k}\Omega \text{ to GND}$		5	7		V
V_{OL}	Low-level output voltage (3)	DOUT	$R_L = 3 \text{ k}\Omega \text{ to GND}$			-7	– 5	V
ro	Output resistance	DOUT	$V_{S+} = V_{S-} = 0,$	$V_O = \pm 2 V$	300			Ω
I _{OS} (4)	Short-circuit output current	DOUT	V _{CC} = 5.5 V,	V _O = 0		±10		mA
I _{IS}	Short-circuit input current	DIN	V _I = 0				200	μΑ

- (1) Test conditions are C1–C4 = 1 μF at V_{CC} = 5 V ± 0.5 V.
 (2) All typical values are at V_{CC} = 5 V and T_A = 25°C.
 (3) The algebraic convention, in which the least-positive (most negative) value is designated minimum, is used in this data sheet for logic voltage levels only.
- (4) Not more than one output should be shorted at a time.

Switching Characteristics⁽¹⁾

 $V_{CC} = 5 \text{ V}, T_A = 25^{\circ}\text{C} \text{ (see Note 4)}$

	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
SR	Driver slew rate	$R_L = 3 \text{ k}\Omega \text{ to 7 k}\Omega$, See Figure 2			30	V/μs
SR(t)	Driver transition region slew rate	See Figure 3		3		V/μs
	Data rate	One DOUT switching		250		kbit/s

⁽¹⁾ Test conditions are C1–C4 = 1 μ F at V_{CC} = 5 V ± 0.5 V.

ESD protection

PARAMETER	TEST CONDITIONS	TYP	UNIT
	НВМ	±15	kV
DOUT, RIN	IEC61000-4-2, Air-Gap Discharge	±15	kV
	IEC61000-4-2, Contact Discharge	±8	kV

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RECEIVER SECTION

Electrical Characteristics⁽¹⁾

over recommended ranges of supply voltage and operating free-air temperature range

	PARAMETER	TEST CON	NDITIONS	MIN	TYP ⁽²⁾	MAX	UNIT	
V_{OH}	High-level output voltage	ROUT	$I_{OH} = -1 \text{ mA}$		3.5			V
V_{OL}	Low-level output voltage (3)	ROUT	I _{OL} = 3.2 mA				0.4	V
V _{IT+}	Receiver positive-going input threshold voltage	RIN	V _{CC} = 5 V,	T _A = 25°C		1.7	2.4	V
V_{IT-}	Receiver negative-going input threshold voltage	RIN	V _{CC} = 5 V,	T _A = 25°C	0.8	1.2		V
V _{hys}	Input hysteresis voltage	RIN	V _{CC} = 5 V		0.2	0.5	1	V
ri	Receiver input resistance	RIN	V _{CC} = 5 V,	T _A = 25°C	3	5	7	kΩ

Switching Characteristics(1)

 $V_{CC} = 5 \text{ V}, T_A = 25^{\circ}\text{C} \text{ (see Figure 1)}$

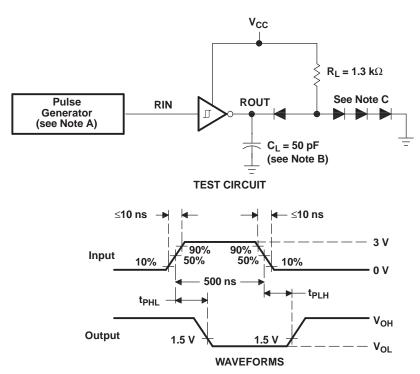
	PARAMETER	TYP	UNIT
t _{PLH(R)}	Receiver propagation delay time, low- to high-level output	500	ns
t _{PHL(R)}	Receiver propagation delay time, high- to low-level output	500	ns

(1) Test conditions are C1–C4 = 1 μ F at V_{CC} = 5 V ± 0.5 V.

Test conditions are C1–C4 = 1 μ F at V_{CC} = 5 V \pm 0.5 V. All typical values are at V_{CC} = 5 V and T_A = 25°C. The algebraic convention, in which the least-positive (most negative) value is designated minimum, is used in this data sheet for logic voltage levels only.



PARAMETER MEASUREMENT INFORMATION

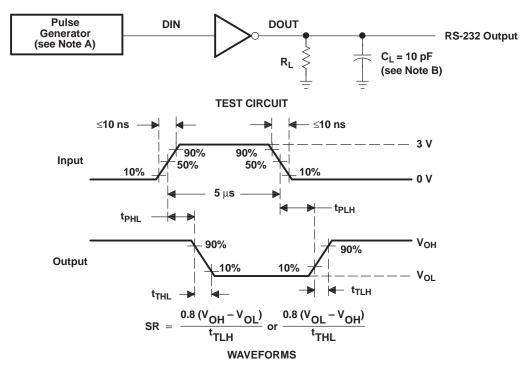


- A. The pulse generator has the following characteristics: $Z_0 = 50 \Omega$, duty cycle $\leq 50\%$.
- B. C_L includes probe and jig capacitance.
- C. All diodes are 1N3064 or equivalent.

Figure 1. Receiver Test Circuit and Waveforms for t_{PHL} and t_{PLH} Measurements

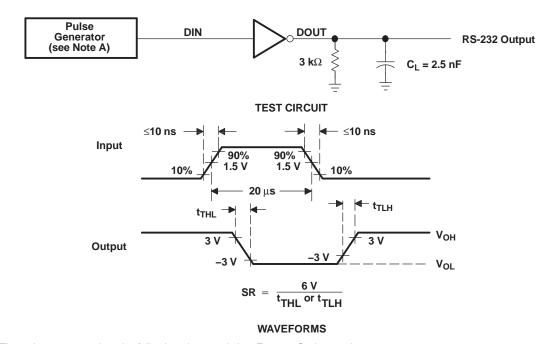


PARAMETER MEASUREMENT INFORMATION (continued)



- A. The pulse generator has the following characteristics: $Z_0 = 50 \Omega$, duty cycle $\leq 50\%$.
- B. C_L includes probe and jig capacitance.

Figure 2. Driver Test Circuit and Waveforms for t_{PHL} and t_{PLH} Measurements (5-µs Input)

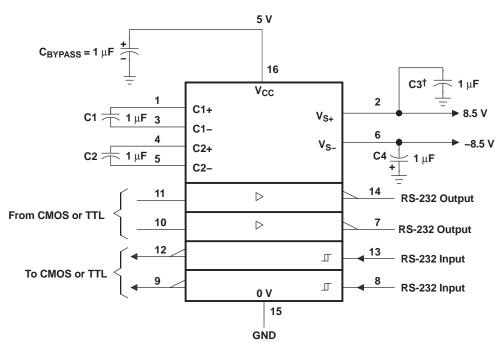


A. The pulse generator has the following characteristics: $Z_0 = 50 \Omega$, duty cycle $\leq 50\%$.

Figure 3. Test Circuit and Waveforms for t_{THL} and t_{TLH} Measurements (20-μs Input)



APPLICATION INFORMATION



 $^{^{\}dagger}$ C3 can be connected to V_{CC} or GND.

- A. Resistor values shown are nominal.
- B. Nonpolarized ceramic capacitors are acceptable. If polarized tantalum or electrolytic capacitors are used, they should be connected as shown. In addition to the 1- μ F capacitors shown, the TRS202E can operate with 0.1- μ F capacitors.

Figure 4. Typical Operating Circuit





14-Sep-2018

PACKAGING INFORMATION

Orderable Device	Status	Package Type	Package Drawing	Pins	Package Qty	Eco Plan	Lead/Ball Finish	MSL Peak Temp	Op Temp (°C)	Device Marking (4/5)	Samples
TRS232ECD	ACTIVE	SOIC	D	16	40	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	0 to 70	TRS232EC	Samples
TRS232ECDR	ACTIVE	SOIC	D	16	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	0 to 70	TRS232EC	Samples
TRS232ECDWR	ACTIVE	SOIC	DW	16	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	0 to 70	TRS232EC	Samples
TRS232ECN	ACTIVE	PDIP	N	16	25	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type	0 to 70	TRS232ECN	Samples
TRS232ECPW	ACTIVE	TSSOP	PW	16	90	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	0 to 70	RU32EC	Samples
TRS232ECPWR	ACTIVE	TSSOP	PW	16	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	0 to 70	RU32EC	Samples
TRS232EID	ACTIVE	SOIC	D	16	40	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	TRS232EI	Samples
TRS232EIDR	ACTIVE	SOIC	D	16	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	TRS232EI	Samples
TRS232EIDWR	ACTIVE	SOIC	DW	16	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	TRS232EI	Samples
TRS232EIN	ACTIVE	PDIP	N	16	25	Green (RoHS & no Sb/Br)	CU NIPDAU	N / A for Pkg Type	-40 to 85	TRS232EIN	Samples
TRS232EIPW	ACTIVE	TSSOP	PW	16	90	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	RU32EI	Samples
TRS232EIPWR	ACTIVE	TSSOP	PW	16	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	RU32EI	Samples

⁽¹⁾ The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

⁽²⁾ RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".



PACKAGE OPTION ADDENDUM

14-Sep-2018

Green: TI defines "Green" to mean the content of Chlorine (CI) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

- (3) MSL, Peak Temp. The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.
- (4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.
- (5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.
- (6) Lead/Ball Finish Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead/Ball Finish values may wrap to two lines if the finish value exceeds the maximum column width.

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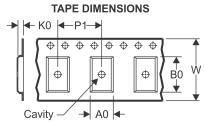
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PACKAGE MATERIALS INFORMATION

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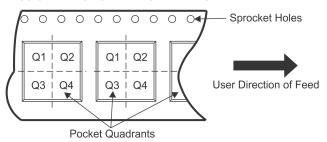
TAPE AND REEL INFORMATION





Α0	Dimension designed to accommodate the component width
	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
TRS232ECDR	SOIC	D	16	2500	330.0	16.4	6.5	10.3	2.1	8.0	16.0	Q1
TRS232ECDR	SOIC	D	16	2500	330.0	16.4	6.5	10.3	2.1	8.0	16.0	Q1
TRS232ECDWR	SOIC	DW	16	2000	330.0	16.4	10.75	10.7	2.7	12.0	16.0	Q1
TRS232ECPWR	TSSOP	PW	16	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1
TRS232EIDR	SOIC	D	16	2500	330.0	16.4	6.5	10.3	2.1	8.0	16.0	Q1
TRS232EIDWR	SOIC	DW	16	2000	330.0	16.4	10.75	10.7	2.7	12.0	16.0	Q1
TRS232EIPWR	TSSOP	PW	16	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1

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*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)	
TRS232ECDR	SOIC	D	16	2500	333.2	345.9	28.6	
TRS232ECDR	SOIC	D	16	2500	367.0	367.0	38.0	
TRS232ECDWR	SOIC	DW	16	2000	350.0	350.0	43.0	
TRS232ECPWR	TSSOP	PW	16	2000	367.0	367.0	35.0	
TRS232EIDR	SOIC	D	16	2500	367.0	367.0	38.0	
TRS232EIDWR	SOIC	DW	16	2000	350.0	350.0	43.0	
TRS232EIPWR	TSSOP	PW	16	2000	367.0	367.0	35.0	

7.5 x 10.3, 1.27 mm pitch

SMALL OUTLINE INTEGRATED CIRCUIT

This image is a representation of the package family, actual package may vary. Refer to the product data sheet for package details.





SOIC



- 1. All linear dimensions are in millimeters. Dimensions in parenthesis are for reference only. Dimensioning and tolerancing
- per ASME Y14.5M.

 2. This drawing is subject to change without notice.

 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.15 mm, per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm, per side.
- 5. Reference JEDEC registration MS-013.



SOIC



NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



SOIC



NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.



N (R-PDIP-T**)

PLASTIC DUAL-IN-LINE PACKAGE

16 PINS SHOWN



- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- Falls within JEDEC MS-001, except 18 and 20 pin minimum body length (Dim A).
- The 20 pin end lead shoulder width is a vendor option, either half or full width.



D (R-PDS0-G16)

PLASTIC SMALL OUTLINE



- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.006 (0,15) each side.
- Body width does not include interlead flash. Interlead flash shall not exceed 0.017 (0,43) each side.
- E. Reference JEDEC MS-012 variation AC.



D (R-PDSO-G16)

PLASTIC SMALL OUTLINE



- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Publication IPC-7351 is recommended for alternate designs.
- D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525 for other stencil recommendations.
- E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.





SMALL OUTLINE PACKAGE



- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

 2. This drawing is subject to change without notice.

 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
- 5. Reference JEDEC registration MO-153.



SMALL OUTLINE PACKAGE



NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



SMALL OUTLINE PACKAGE



NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.



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